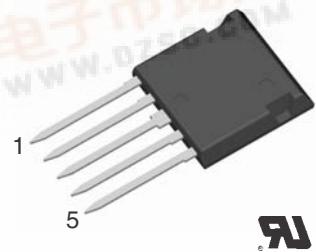
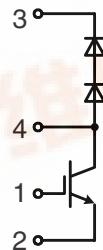




## Fast IGBT Chopper in ISOPLUS i4-PAC™

Preliminary data

$I_{C25}$  = 38 A  
 $V_{CES}$  = 600 V  
 $V_{CE(sat)\text{typ.}}$  = 1.9 V



### IGBT

Symbol	Conditions	Maximum Ratings		
$V_{CES}$	$T_{VJ} = 25^\circ\text{C}$ to $150^\circ\text{C}$	600		V
$V_{GES}$		$\pm 20$		V
$I_{C25}$	$T_c = 25^\circ\text{C}$	38		A
$I_{C90}$	$T_c = 90^\circ\text{C}$	24		A
$I_{CM}$	$V_{GE} = \pm 15 \text{ V}$ ; $R_G = 10 \Omega$ ; $T_{VJ} = 125^\circ\text{C}$	110		A
$V_{CEK}$	RBSOA, Clamped inductive load; $L = 100 \mu\text{H}$	$V_{CES}$		
$t_{sc}$ (SCSOA)	$V_{CE} = V_{CES}$ ; $V_{GE} = \pm 15 \text{ V}$ ; $R_G = 10 \Omega$ ; $T_{VJ} = 125^\circ\text{C}$ non-repetitive	10		$\mu\text{s}$
$P_{tot}$	$T_c = 25^\circ\text{C}$	125		W

Symbol	Conditions	Characteristic Values		
		( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)	min.	typ.
$V_{CE(sat)}$	$I_C = 25 \text{ A}$ ; $V_{GE} = 15 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	1.9	2.4	V
		2.2		V
$V_{GE(th)}$	$I_C = 0.7 \text{ mA}$ ; $V_{GE} = V_{CE}$	3	5	V
$I_{CES}$	$V_{CE} = V_{CES}$ ; $V_{GE} = 0 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	1	0.04	mA
$I_{GES}$	$V_{CE} = 0 \text{ V}$ ; $V_{GE} = \pm 20 \text{ V}$		200	nA
$t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$ $E_{on}$ $E_{off}$	Inductive load, $T_{VJ} = 125^\circ\text{C}$ $V_{CE} = 300 \text{ V}$ ; $I_C = 25 \text{ A}$ $V_{GE} = \pm 15 \text{ V}$ ; $R_G = 10 \Omega$	30 50 320 70 1.1 0.6		ns ns ns ns mJ mJ
$C_{ies}$ $Q_{Gon}$	$V_{CE} = 25 \text{ V}$ ; $V_{GE} = 0 \text{ V}$ ; $f = 1 \text{ MHz}$ $V_{CE} = 600 \text{ V}$ ; $V_{GE} = 15 \text{ V}$ ; $I_C = 15 \text{ A}$	1.6 140		nF nC
$R_{thJC}$ $R_{thJH}$	(with heat transfer paste)	2.0	1.0	K/W K/W

### Features

- NPT IGBT technology
  - low switching losses for high frequency operation
  - no latch up
  - positive temperature coefficient for easy paralleling
- HiPerDyn™ FRED
  - consisting of series connected diodes
  - enhanced dynamic behaviour for high frequency operation
- ISOPLUS i4-PAC™ package
  - isolated back surface
  - low coupling capacity between pins and heatsink
  - enlarged creepage towards heatsink
  - application friendly pinout
  - low inductive current path
  - high reliability
  - industry standard outline
  - UL registered E 72873

### Applications

- boost chopper for power factor correction
- supply of high frequency transformer
  - switched mode power supplies
  - welding converters

**Diodes (data for series connection)**

Symbol	Conditions	Maximum Ratings		
$V_{RRM}$	$T_{VJ} = 25^\circ\text{C}$ to $150^\circ\text{C}$	600		V
$I_{F25}$	$T_C = 25^\circ\text{C}$	35		A
$I_{F90}$	$T_C = 90^\circ\text{C}$	20		A

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
$V_F$	$I_F = 25 \text{ A}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	2.8 2.2	3.7 V	V
$I_R$	$V_R = V_{RRM}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	0.1	0.1 mA mA	
$I_{RM}$ $t_{rr}$	$\left. \begin{array}{l} I_F = 15 \text{ A}; dI_F/dt = -400 \text{ A}/\mu\text{s}; T_{VJ} = 125^\circ\text{C} \\ V_R = 300 \text{ V}; V_{GE} = 0 \text{ V} \end{array} \right\}$	8 50		A ns
$R_{thJC}$ $R_{thJH}$	(per diode)	2.3	1.2 K/W K/W	

**Component**

Symbol	Conditions	Maximum Ratings		
$T_{VJ}$		-55...+150		°C
$T_{stg}$		-55...+125		°C
$V_{ISOL}$	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$	2500		V~
$F_c$	mounting force with clip	20...120		N

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
$C_p$	coupling capacity between shorted pins and mounting tab in the case	40		pF
$d_s d_A$	pin - pin	1.7		mm
$d_s d_A$	pin - backside metal	5.5		mm
<b>Weight</b>		9		g

**Dimensions in mm (1 mm = 0.0394")**
